

SD1477

RF POWER BIPOLAR TRANSISTORS VHF MOBILE APPLICATIONS

FEATURES SUMMARY

- 175 MHz
- 12.5 VOLTS
- COMMON EMITTER
- P_{OUT} = 100 W MIN. WITH 6.0 dB GAIN

DESCRIPTION

The SD1477 is a 12.5 V Class C epitaxial silicon NPN planar transistor designed primarily for VHF FM communications. This device utilizes diffused emitter resistors to withstand extremely high VSWR under rated operating conditions, and is internally input matched to optimize power gain and efficiency over the 136 - 175 MHz band.

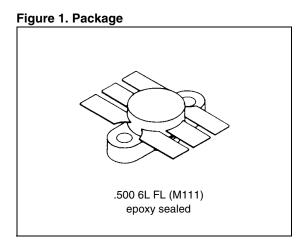


Figure 2. Pin Connection

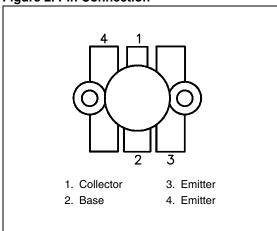


Table 1. Order Codes

Order Codes	Marking	Package	Packaging
SD1477	SD1477	M111	PLASTIC TRAYS

REV. 2

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Table 2. Absolute Maximum Ratings (T_{case} = 25°C)

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	36	V	
V _{CEO}	Collector-Emitter Voltage	18	V	
V _{CES}	Collector-Emitter Voltage	36	V	
V _{EBO}	Emitter-Base Voltage	4.0	V	
I _C Device Current		20	Α	
P _{DISS} Power Dissipation		270	W	
T _J Junction Temperature		+200	°C	
T _{STG} Storage Temperature		- 65 to +150	°C	

Table 3. Thermal Data

Symbol Parameter		Value	Unit
R _{TH(j-c)}	Junction-Case Thermal Resistance	0.65	°C/W

ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

Table 4. Static

Symbol	Test Conditions	Value			Unit
Symbol	rest conditions	Min.	Тур.	Max.	Oilit
BV _{CBO}	I _C = 50 mA; I _E = 0 mA		_	_	V
BV _{CES}	I _C = 100 mA; V _{BE} = 0 V	36	_	_	V
BV _{CEO}	I _C = 100 mA; I _B = 0 mA	18	_	_	V
BV _{EBO}	I _E = 10 mA; I _C = 0 mA	4.0	_	_	V
I _{CES}	V _{CE} = 15 V; I _E = 0 mA	_	_	15	mA
h _{FE}	V _{CE} = 5 V; I _C = 5 A	10	_	_	_

Table 5. Dynamic

Symbol	Test Conditions	Value			Unit
Symbol	rest conditions	Min.	Тур.	Max.	Oiiit
Роит	f = 175 MHz; P _{IN} = 25 W; V _{CC} = 12.5 V	100	_	_	W
G _P	f = 175 MHz; P _{IN} = 25 W; V _{CC} = 12.5 V	6.0	_	_	dB
C _{OB}		_	350	_	pF

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TYPICAL PERFORMANCE

Figure 3. Power Output vs Frequency

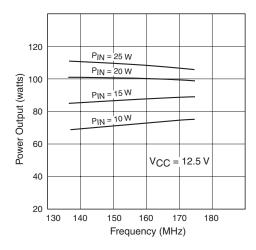
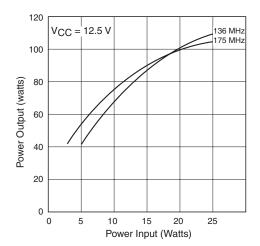


Figure 4. Power Output vs Power Input



IMPEDANCE DATA

Figure 5. Typical Input Impedance

(Study) 90 US HOLD 150 160 170 180 190 Power Input (Watts)

Figure 6. Typical Collector Load Impedance

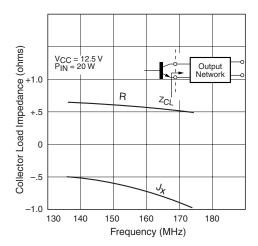


Table 6. Impedance Data

FREQ.	Z _{IN} (Ω)	Z _{CL} (Ω)
175 MHz	1.5 – j 0.9	0.5 – j 1.0

TEST CIRCUIT

Figure 7. Test Circuit

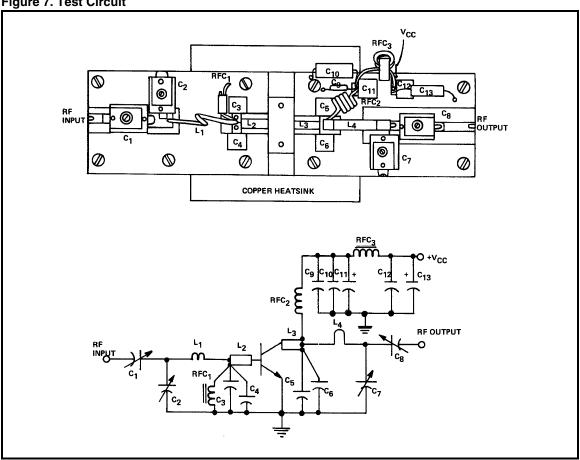
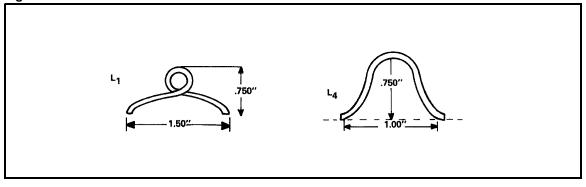


Table 7. Test Circuit

C1, C2	Arco 462 5 - 80pF	
C3, C4	Unelco 100pF, 350V	
C5, C6	Unelco 120pF, 350V	
C7, C8	Arco 463 9 - 180pF	
C9, C12	Unelco 1000pF, 350V	
C10	Erie .15μF, 200V Red Cap	
C11	25μF, 25V Electrolytic	
C13	10μF, 25V Electrolytic	
L1	1 Turn, #12, 1/4" I.D.	
L2, L3	1/2" 50Ω Stripline (.180" Wide)	
L4	1/8" Thick Copper Strap 1/4" Wide	
RCF1	1 1/2 Turns on Ferroxcube VK200/19-B	
RCF2	4 Turn #16 Enamel, 3/8" I.D., 3/8" Long	
RCF3	4 Turns #16 Enamel on T50-2 Torroid	
Board Material	3M-K6098, 1/16" Thick	

Figure 8. Test Circuit

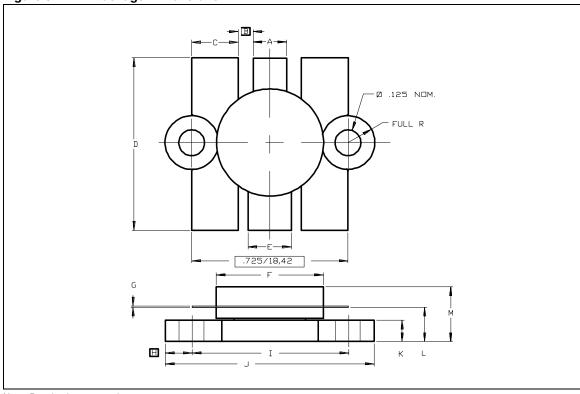


PACKAGE MECHANICAL

Table 8. M111 Mechanical Data

Cumbal	millimeters		inches			
Symbol	Min	Тур	Max	Min	Тур	Max
Α	3.43		4.06	0.150		0.160
В		1.14			0.045	
С	5.33		5.59	0.210		0.220
D	21.21		21.97	0.835		0.865
E	5.08		5.33	0.200		0.210
F	12.45		12.95	0.490		0.510
G	0.08		0.18	0.003		0.007
Н		3.18			0.125	
I	18.29		18.54	0.720		0.730
J	24.64		24.89	0.970		0.980
K	2.41		2.67	0.095		0.105
L	3.81		4.32	0.150		0.170
М			7.11			0.280

Figure 9. M111 Package Dimensions



Note: Drawing is not to scale.

SD1477

REVISION HISTORY

Table 9. Revision History

Date	Revision	Description of Changes
November-1992	1	First Issue
7-June-2004	2	Stylesheet update. No content change.

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